## NSN 5962-01-096-1162



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-096-1162 **Body Length:** 1.100 inches **Body Width:** Between 0.380 inches and 0.400 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 1.25 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 20 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 500.00 nanoseconds propagation delay time, low to high level output and 500.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 22 printed circuit Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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